NSN 5961-00-760-1173

Diode Semiconductor Device - Page 1 of 1



View Online at https://aerobasegroup.com/nsn/5961-00-760-1173 **Inclosure Material:** Metal **Overall Length:** 0.375 inches **Overall Diameter:** 0.280 inches **Mounting Facility Quantity: Mounting Method:** Threaded stud **Features Provided:** Hermetically sealed case **Overall Width Across Flats:** 0.438 inches **Thread Size:** 0.190 inches **Semiconductor Material:** Silicon Voltage Rating In Volts Per Characteristic: 24.0 regulator voltage **Current Rating Per Characteristic:** 400.00 milliamperes source cutoff current horsepower metric **Power Rating Per Characteristic:** 100.0 milliwatts small-signal input power, common-collector **Maximum Operating Tempurature Per Measurement Point:** 150.0 degrees celsius ambient air **Thread Series Designator:** Unf **Terminal Type And Quantity:** 1 threaded stud and 1 tab, solder lug Shelf Life: N/a **Unit Of Measure: Demilitarization:**

No

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